

## Semiconductor/Superconductor Transition of $\text{La}_2\text{CuO}_4$ via Chemical Oxidation at Ambient Temperature

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The oxocuprate semiconductor  $\text{La}_2\text{CuO}_4$  can be converted reversibly to a superconductor with  $T_c = 44$  K by simple chemical oxidation with hypohalites at room temperature.

High temperature superconductivity was first observed for the  $\text{La}_2\text{CuO}_4$  system, which has remained of basic interest owing to its compositional and structural simplicity.<sup>1</sup> The oxocuprate has a  $\text{K}_2\text{NiF}_4$  type anisometric structure and can be converted into a superconductor with  $\text{Cu}^{2+}/\text{Cu}^{3+}$  mixed valence state by

(i) thermal preparation of phases with partial isomorphous replacement  $\text{La}^{3+} \rightarrow \text{M}^{2+}$  ( $\text{M} = \text{Ca}, \text{Sr}, \text{Ba}$ ) or (ii) by treatment with molecular oxygen at high pressures (0.2–23 kbar) above 600 °C.<sup>2–4</sup> (iii) A most unusual process that has been reported recently is the anodic electrochemical treat-

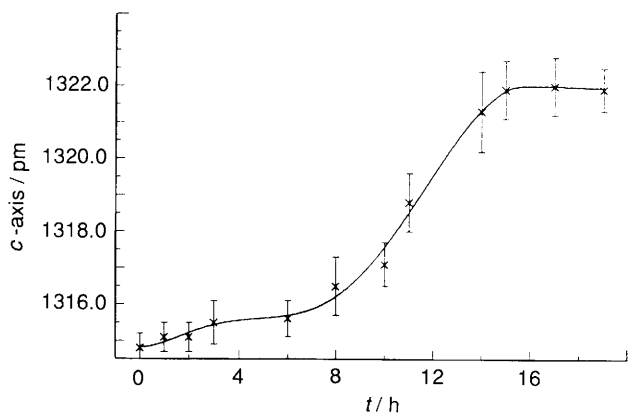


Fig. 1 Kinetics of the oxidation process: change of the lattice parameter  $c$  with  $t$  during oxidation of  $\text{La}_2\text{CuO}_4$  by  $1 \text{ mol dm}^{-3}$   $\text{NaOBr}$  at  $300 \text{ K}$

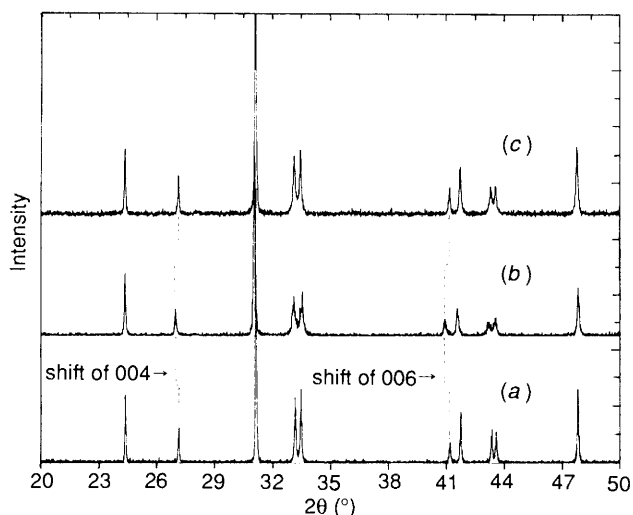


Fig. 2 X-ray diffractograms (Cu-K-radiation): (a) of pristine  $\text{La}_2\text{CuO}_4$ , (b) of  $\text{La}_2\text{CuO}_4$  oxidized by  $\text{NaOBr}$  and (c) of oxidized  $\text{La}_2\text{CuO}_4$  reduced subsequently by hydrazine hydrate; shift changes of 001 reflections are indicated by dashed lines

ment of the cuprate in aqueous alkaline electrolyte at ambient temperature.<sup>5</sup> In extension of our earlier investigations on the mechanism of this reaction<sup>6</sup> we now have found a most simple, convenient and efficient chemical oxidation process for the conversion of  $\text{La}_2\text{CuO}_4$  at room temperature to a superconductor with  $T_c = 44 \text{ K}$  and for the inverse reaction, *i.e.* the chemical reduction of the superconducting phase to the semiconducting state. Systematic screening studies revealed that alkali hypochlorites and hypobromites are able to react with  $\text{La}_2\text{CuO}_4$  in a topotactic process under retention of the host lattice. A simple and reliable procedure is *e.g.* to treat a suspension of  $1 \text{ g}$  of  $\text{La}_2\text{CuO}_4$  in an alkaline sodium hypobromite solution (prepared from  $100 \text{ ml}$   $5 \text{ mol dm}^{-3}$  aqueous  $\text{NaOH}$  at  $0^\circ\text{C}$  by addition of  $2.5 \text{ ml}$   $\text{Br}_2$ ) under strong stirring for  $12\text{--}16 \text{ h}$ . The black solid product is then filtered off, washed with water and acetone and dried in vacuum at  $10^{-3} \text{ mbar}/300 \text{ K}$ .

The change in the average oxidation state of copper during the reaction can be determined by iodometric titration; the  $\text{Cu}^{3+}$  content calculated from these data was  $0.000(5)$  for the starting material and  $0.145(5)$  for the oxidized product. The kinetics of the reaction were also checked *via* the change of the lattice parameters; Fig. 1 demonstrates the S shaped conversion curve which is assumed to originate from surface kinetic

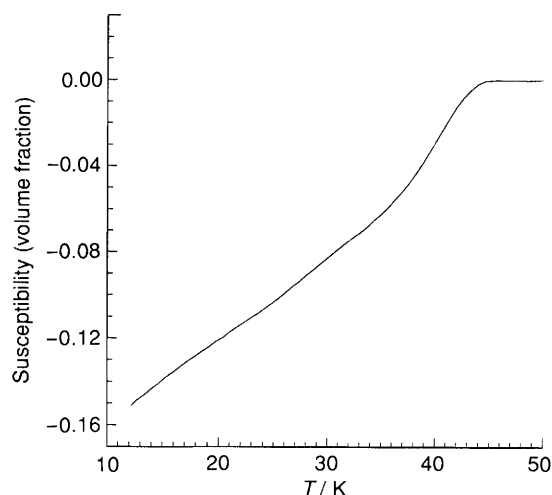


Fig. 3 AC-susceptibility vs.  $T/\text{K}$  for  $\text{La}_2\text{CuO}_4$  oxidized by  $\text{NaOBr}$

hindrance of the electron/ion transfer process in the starting region of the solid state reaction. Under the conditions described the reaction comes to an end after about  $15 \text{ h}$ , no further change in lattice parameters or average oxidation state is found thereafter.

X-Ray diffractograms show a slight increase of the line width of the product as compared to the starting phase, which is normal for a solid state process at ambient temperature as a consequence of a finite increase in defect concentration (Fig. 2).

The lattice parameters (pm) change from  $a = 540.0(2)$ ,  $b = 535.3(2)$ ,  $c = 1314.1(4)$  and  $V = 379.86 \times 10^6 \text{ pm}^3$  for pristine  $\text{La}_2\text{CuO}_4$  to  $a = 540.7(2)$ ,  $b = 533.8(2)$ ,  $c = 1321.3(4)$  and  $V = 381.4 \times 10^6 \text{ pm}^3$  for the reaction product. The total change in unit cell volume of  $0.4\%$  is rather small.

The temperature dependence of the magnetic susceptibility (Fig. 3) indicates a sharp  $T_c(\text{onset})$  at  $44 \text{ K}$  with a superconducting volume fraction of  $14\%$  at  $12 \text{ K}$  (powder samples). The volume fraction observed is compatible with that found for polycrystalline phases prepared at high oxygen pressure at  $600^\circ\text{C}$ .<sup>3</sup> The width of the transition is a consequence of the polycrystalline nature of the samples and is comparable to the transition width of samples obtained *via* electrosynthesis.

Heating beyond  $400^\circ\text{C}$  leads to total loss of the superconducting properties. Differential thermal analysis and thermogravimetric studies show that the thermal decomposition process occurs stepwise.

We found that the oxidized superconducting phase can be reduced chemically at  $300 \text{ K}$  by a wide series of reagents with varying standard reduction potentials from  $-1.87$  to  $0.08 \text{ V}$  ( $\text{NH}_2\text{OH}$ ,  $\text{N}_2\text{H}_5\text{OH}$ ,  $\text{S}_2\text{O}_4^{2-}$ ,  $\text{SO}_3^{2-}$ ,  $\text{H}_2\text{O}_2$ ,  $\text{S}_2\text{O}_3^{2-}$ ). Particularly fast kinetics of the reduction process were observed for hydrazine hydrate. The lattice parameters of the products were found to be identical with those of  $\text{La}_2\text{CuO}_4$  (see also Fig. 2); the samples have lost their superconducting properties and analytical investigations show that all  $\text{Cu}^{3+}$  has been reduced to  $\text{Cu}^{2+}$ .

Although the oxidation reaction described is experimentally straightforward and well reproducible, leading to a terminal product that can be clearly characterized in terms of oxidation state, lattice parameters and superconducting properties the mechanism of the reaction is unclear so far.

The process leading to a  $\text{Cu}^{2+}/\text{Cu}^{3+}$  mixed valence state can presently be explained by two different electron/ion transfer models: (i) intercalation of oxygen into the  $\text{La}_2\text{CuO}_4$  lattice and formation of  $\text{La}_2\text{CuO}_{4+x}$ <sup>5</sup> and (ii) an oxidative electron/proton transfer process as a consequence of La-defects in the pristine material, compensated by OH-groups.<sup>6</sup> Although we

have proposed earlier a model for the high mobility of oxygen in  $\text{YBa}_2\text{Cu}_3\text{O}_{7-x}$  type superconductors (beginning at ca. 300–400 °C) on grounds of oxygen anion radical transport ( $\text{O}^{\cdot-}$ )<sup>7,8</sup> it remains unclear presently whether such a mechanism may operate with reasonable kinetics at temperatures as low as 300 K.

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